

SMD LED LAMP, BI-COLOR

BL-LS1311xx

Features:

- Ø 3.5mmx2.8mm SMD, 1.9mm THICKNESS PLCC4 package
- Ø BI-COLOR TYPE
- Ø Compatible with automatic placement equipment
- Ø WIDE VIEWING ANGLE.
- Ø IDEAL FOR BACKLIGHT AND INDICATOR.
- Ø PACKAGE: 2KPCS/REEL
- Ø RoHs Compliance



Electrical-optical characteristics: (Ta=25°C) (Test Condition: IF=20mA)

Part Number	Chip			Lens Type	Forward Voltage(VF) Unit:V		Luminous Intensity (Iv) Unit:mcd		Viewing Angle 2θ/2 (deg)
	Emitted Color	Material	λp (nm)		Typ	Max	Min.	Typ.	
					BL-LS1311EGC	Orange	GaAsP	640	
	Green	GaP	568	2.30	2.70	28	50		
BL-LS1311UYUGC	Ultra Yellow	AlInGaP	590	2.10	2.60	50	120		
	Ultra Green	AlInGaP	575	2.20	2.70	50	80		
BL-LS1311UEUGC	Ultra Orange	AlInGaP	623	2.10	2.60	110	180		
	Ultra Green	AlInGaP	575	2.20	2.70	50	80		

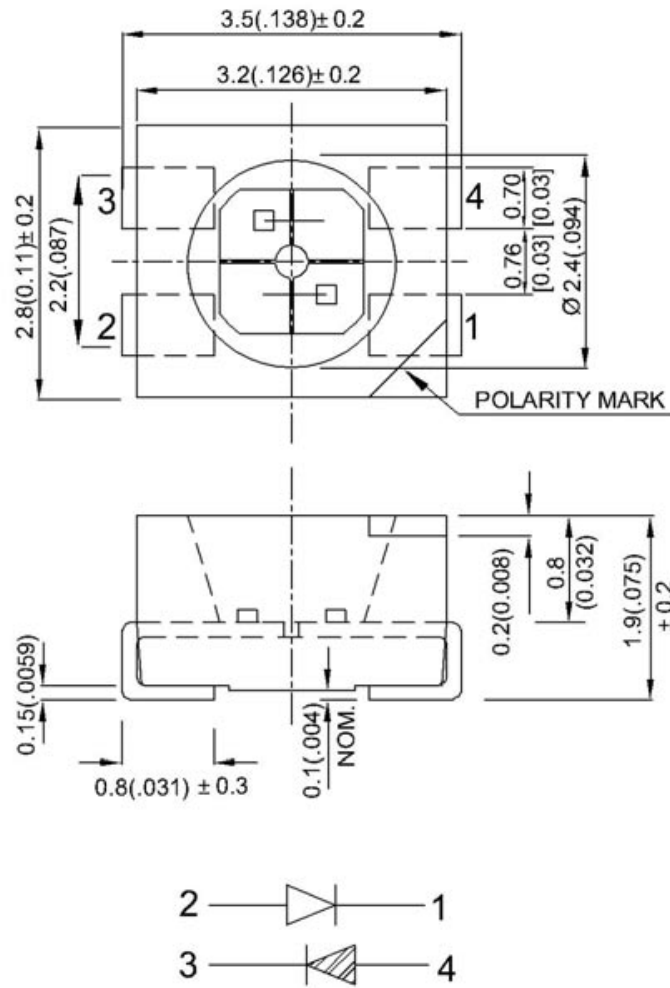
Absolute maximum ratings (Ta=25°C)

Parameter	Rating	Unit
Forward Current I _F	30	mA
Power Dissipation P _d	78	mW
Reverse Voltage V _R	5	V
Peak Forward Current I _{PF} (Duty 1/10 @1KHZ)	100	mA
Operation Temperature T _{OPR}	-30 to +80	°C
Storage Temperature T _{STG}	-40 to +85	°C
Lead Soldering Temperature T _{SOL}	Max.260±5°C for 3 sec Max. (1.6mm from the base of the epoxy bulb)	°C

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Package configuration & Internal circuit diagram



Notes:

1. All dimensions are in millimeters (inches)
2. Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
3. Specifications are subject to change without notice.

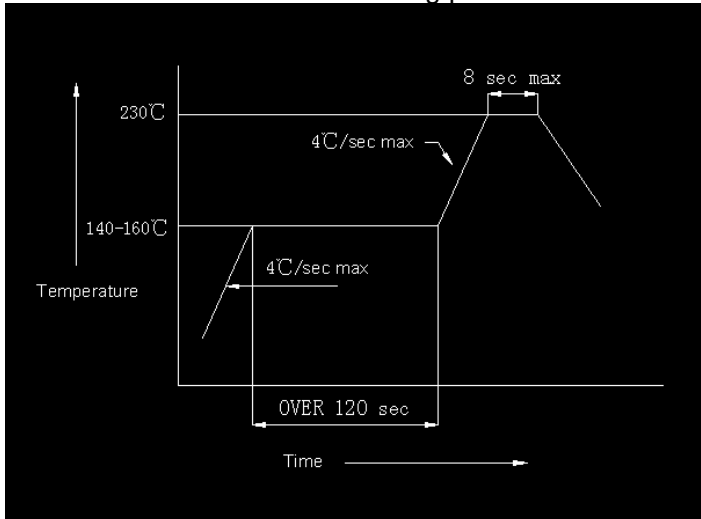
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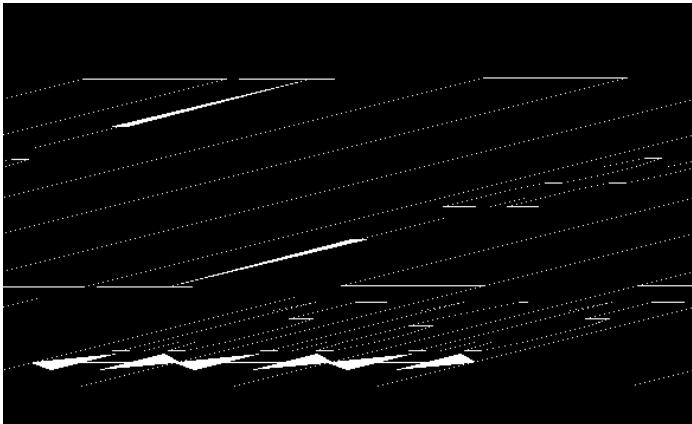
Tape Specifications

Smt Reflow Soldering Instructions

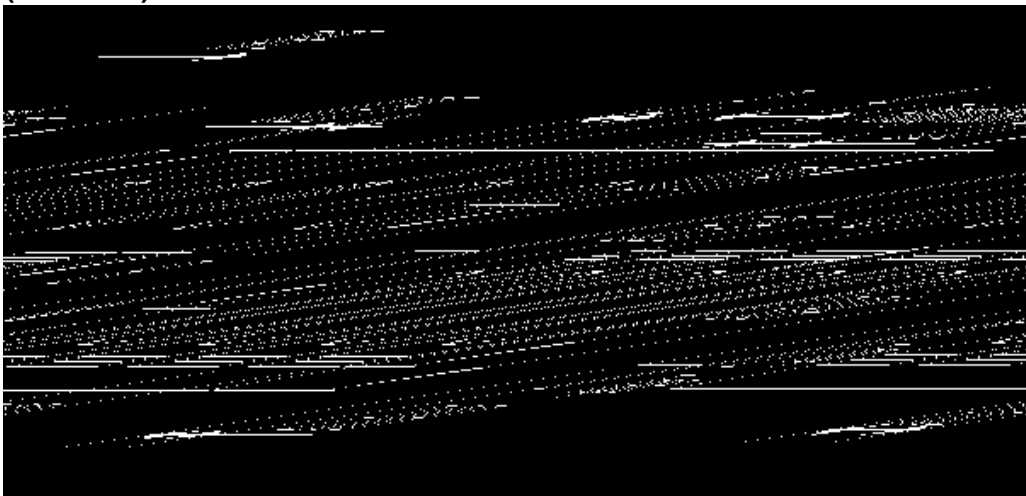
Number of reflow process shall be less than 2 times and cooling process to normal temperature is required between first and second soldering process



Recommended Soldering Pattern (Units:mm)



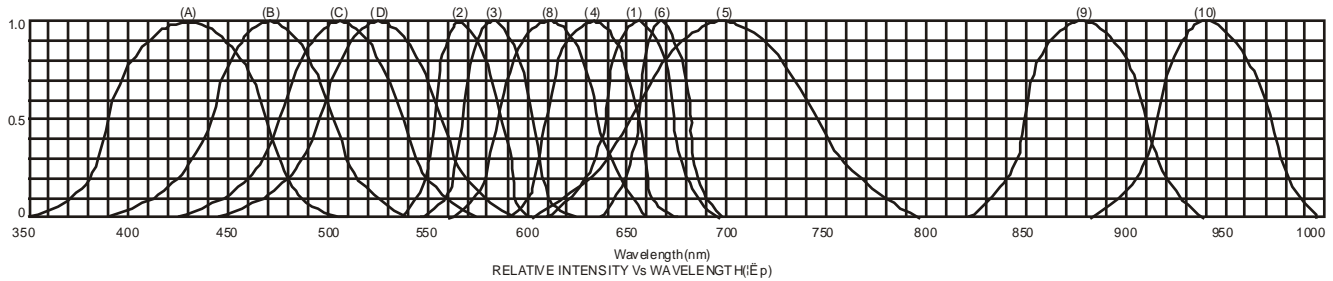
Tape Specifications (Units:mm)



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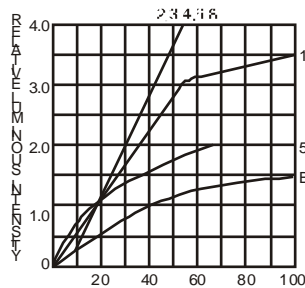
Typical electrical-optical characteristics curves:



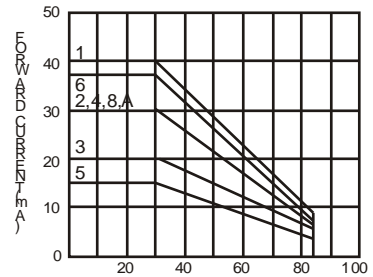
- (1) - GaAsP/GaAs 655nm/Red
- (2) - GaP 570nm/Yellow Green
- (3) - GaAsP/GaP 585nm/Yellow
- (4) - GaAsP/GaP 635nm/Orange & Hi-Eff Red
- (5) - GaP 700nm/Bright Red
- (6) - GaAlAs/GaAs 660nm/Super Red
- (8) - GaAsP/GaP 610nm/Super Red
- (9) - GaAlAs 880nm
- (10) - GaAs/GaAs & GaAlAs/GaAs 940nm
- (A) - GaN/SiC 430nm/Blue
- (B) - InGaN/SiC 470nm/Blue
- (C) - InGaN/SiC 505nm/Ultra Green
- (D) - InGaAlSiC 525nm/Ultra Green



FORWARD VOLTAGE (Vf)
FORWARD CURRENT VS.
FORWARD VOLTAGE



FORWARD CURRENT (mA)
RELATIVE LUMINOUS
INTENSITY VS. FORWARD
CURRENT



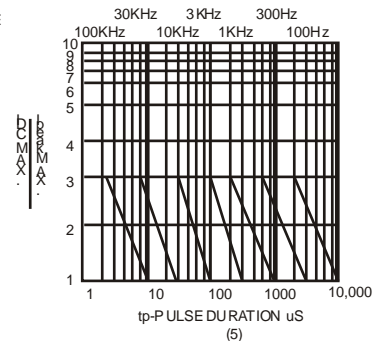
AMBIENT TEMPERATURE Ta ()
FORWARD CURRENT VS. AMBIENT
TEMPERATURE



AMBIENT TEMPERATURE Ta ()



tp-PULSE DURATION μ s
(1,2,3,4,6,8,B,D,J,K)



(5)

NOTE:25 free air temperature unless otherwise specified

Packing and weighting

